



DESCRIPTION

The DS32W~DS320W are available in SOD-123FL package

ORDERING INFORMATION

Package Type	Part Number
SOD-123FL	DS32W
	DS34W
	DS36W
	DS38W
	DS310W
	DS312W
	DS315W
	DS320W
Note	SPQ: 3,000pcs/Reel
AiT provides all RoHS Compliant Products	

PIN DESCRIPTION



FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Available in SOD-123FL package

MECHANICAL DATA

Case: SOD-123FL

Terminals: Solderable per MIL-STD-750,
Method 2026

Approx. Weight: 15mg 0.00048oz



ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbol	DS32W	DS34W	DS36W	DS38W	DS310W	DS312W	DS315W	DS320W	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS Voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	3.0								A
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	80				70				A
Max Instantaneous Forward Voltage at 3A	V_F	0.55		0.70		0.85		0.95		V
Maximum DC Reverse Current at Rated DC Blocking Voltage	I_R	$T_A=25^\circ\text{C}$ 0.5 $T_A=100^\circ\text{C}$ 10		0.3 5						mA
Typical Junction Capacitance ^{NOTE1}	C_J	250			160					pF
Typical Thermal Resistance ^{NOTE2}	$R_{\theta JA}$	65								°C/W
Operating Junction Temperature Range	T_J	-55 ~ +125								°C
Storage Temperature Range	T_{STG}	-55 ~ +150								°C

NOTE1: Measured at 1MHz and applied reverse voltage of 4V D.C.

NOTE2: P.C.B. mounted with 0.2 x 0.2" (5 x 5 mm) copper pad areas.



TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

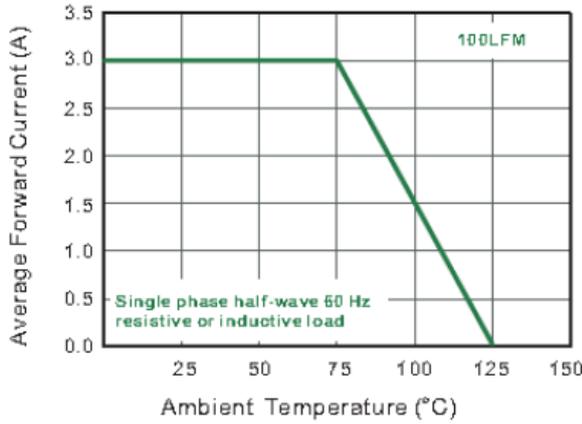


Figure. 2 Typical Reverse Characteristics

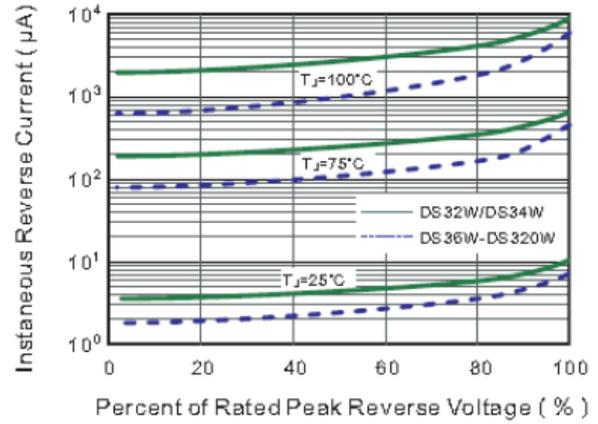


Figure. 3 Typical Forward Characteristic

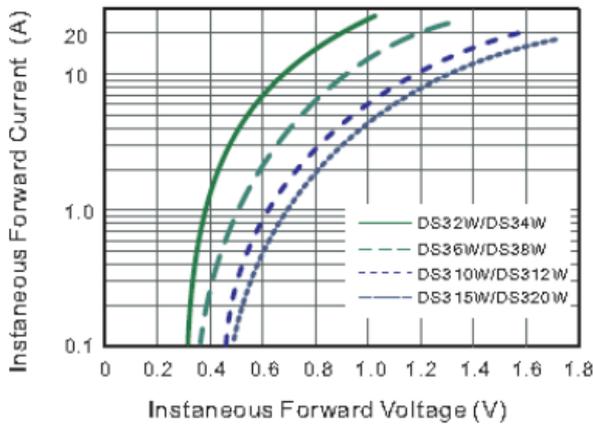


Figure. 4 Typical Junction Capacitance

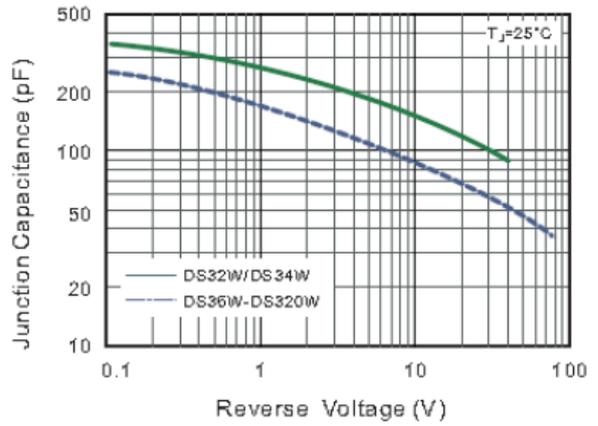


Figure. 5 Maximum Non-Repetitive Peak Forward Surge Current

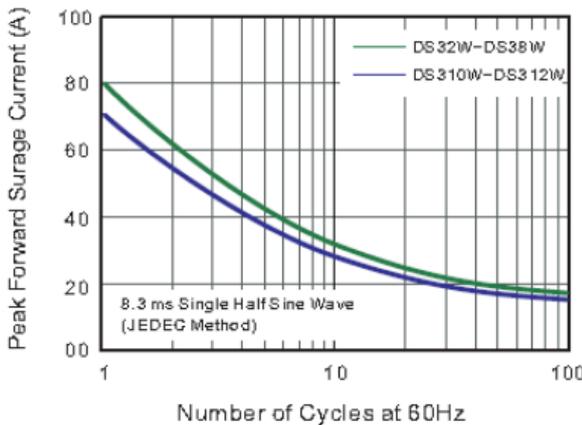
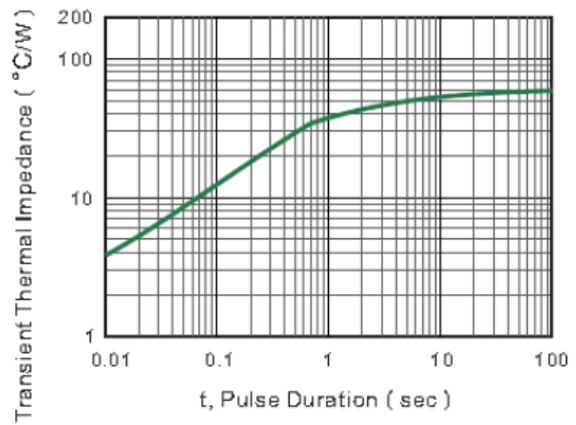


Figure. 6 Typical Transient Thermal Impedance

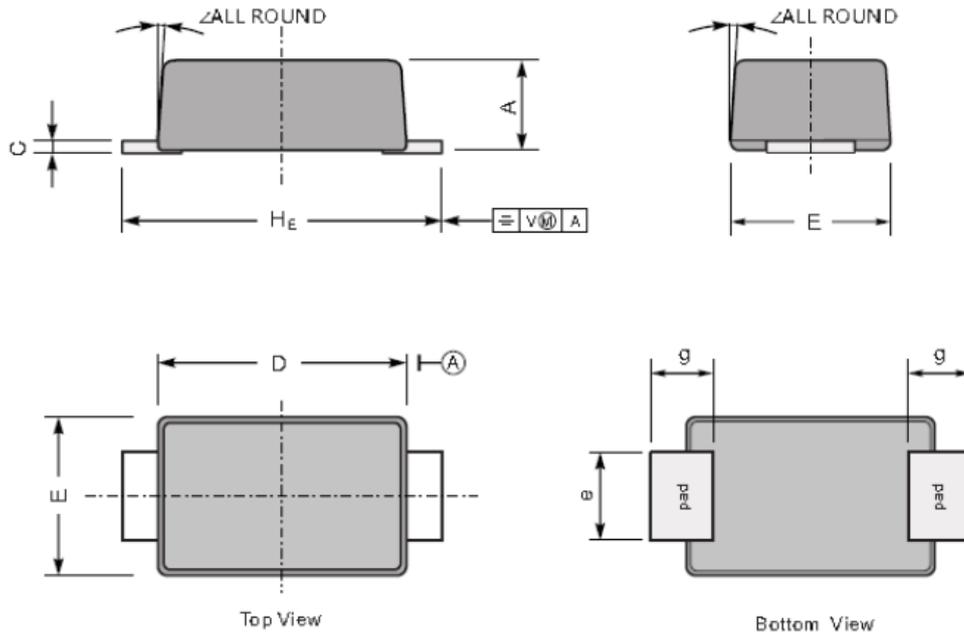




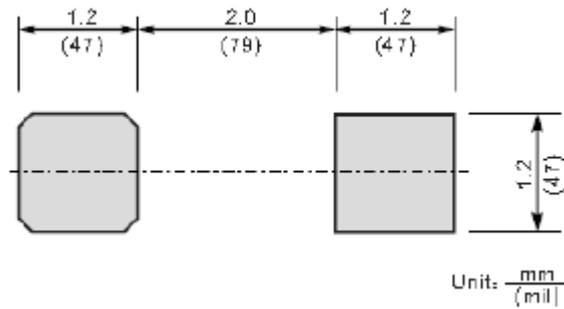
PACKAGE INFORMATION

Dimension in SOD-123FL (Unit: mm)

Plastic surface mounted package; 2 leads



The recommended mounting pad size



Unit: $\frac{\text{mm}}{\text{mil}}$

UNIT		A	C	D	E	e	g	H _E	∠
mm	Max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	Min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	Max	43	7.9	114	75	43	35	150	
	Min	35	4.7	102	67	31	23	138	



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